

Low Power, High Accuracy, Low Cost Offline Switcher

FEATURES

- Low Cost BUCK, Very Few Component
- Fast Startup: 50mS
- Low Standby Power: 50mW
- High Accuracy: $\pm 3\%$
- Fixed 47KHz Frequency
- $\pm 5\%$ Frequency Jittering, improving EMI
- Integrated 500V Power MOS and 500V Startup MOS
- OVP, OTP, OCP, SCP
- AC Input Range: 85~264Vac
- DC input Range: 30~380Vdc
- Package: TO-92, SOT23-3

TYPICAL APPLICATION

- Small Home Appliance
- Auxiliary Supplies
- Linear or RCC Power Replacement

DESCRIPTION

HM2710B is a high performance, high accuracy, low cost buck power switcher, which integrates a peak-current mode PWM controller and a 500V Power MOS.

HM2710B integrates the 500V startup MOS and the current sense resistor, to reduce external component. Internal frequency jittering and soft-driver can effectively improve EMI performance.

HM2710B provides function of over-voltage protection, over-temperature protection, circle by circle over-current protection, output short circuit protection, to prevent the circuit being damaged from the abnormal conditions.

HM2710B is available in package of TO-92 and SOT23-3.

TYPICAL APPLICATION CIRCUIT

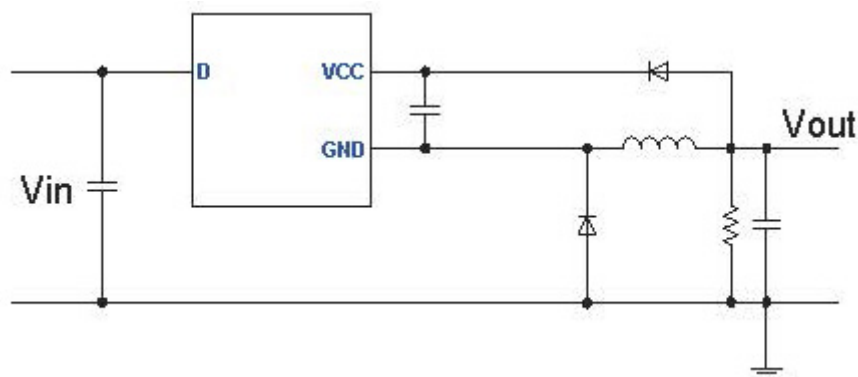


Figure 1: Typical Application

ABSOLUTE MAXIMUM RATINGS

VCC.....	-0.3V~7V
D.....	-0.3V~500V
Junction to Ambient Thermal Resistance(θ_{JA}).....	150°C/W
Operating Temperature Range.....	-40°C to +85°C
Junction Temperature Range.....	-40°C to +150°C
Storage Temperature Range.....	-55°C to +150°C
ESD, Human Body Model.....	2KV
Lead Temperature.....	300°C

***Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.**

Recommended Operating Condition

AC Vin.....	85~264Vac
DC Vin.....	30~380Vdc
Ambient Temperature.....	-40~65°C

PIN Definition and Marking Rule

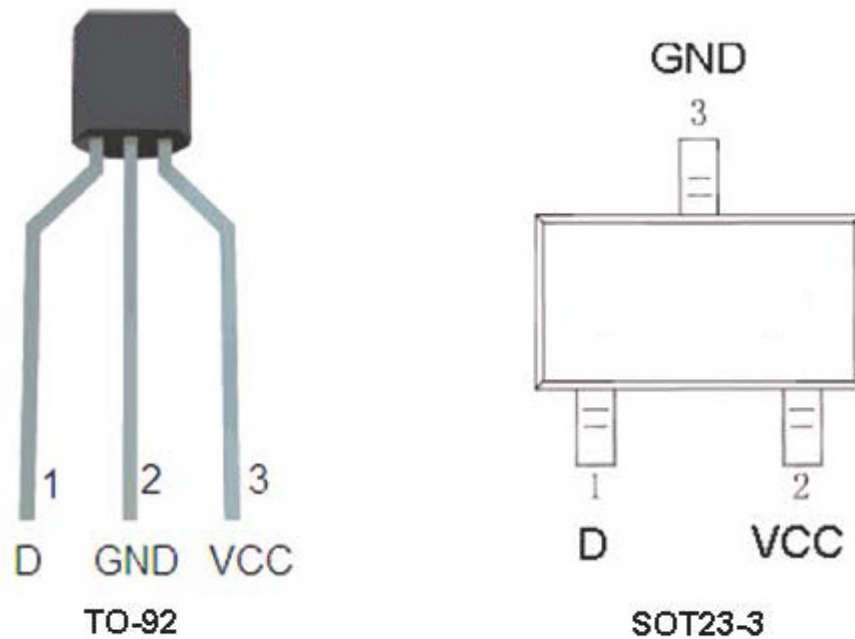


Figure 2: Package Top View

Pin Definition

TO-92	SOT23-3	Name	Description
1	1	D	Drain of MOSFET
2	3	GND	Ground for the chip, and the source of Power MOS
3	2	VCC	Power Supply

Table 1 HM2710B Pin Description

Maximum Output Current

Package	Maximum output current @180~264Vac	Maximum output current @90~264Vac
TO-92	130mA	120mA
SOT23-3	120mA	110mA

Block Diagram

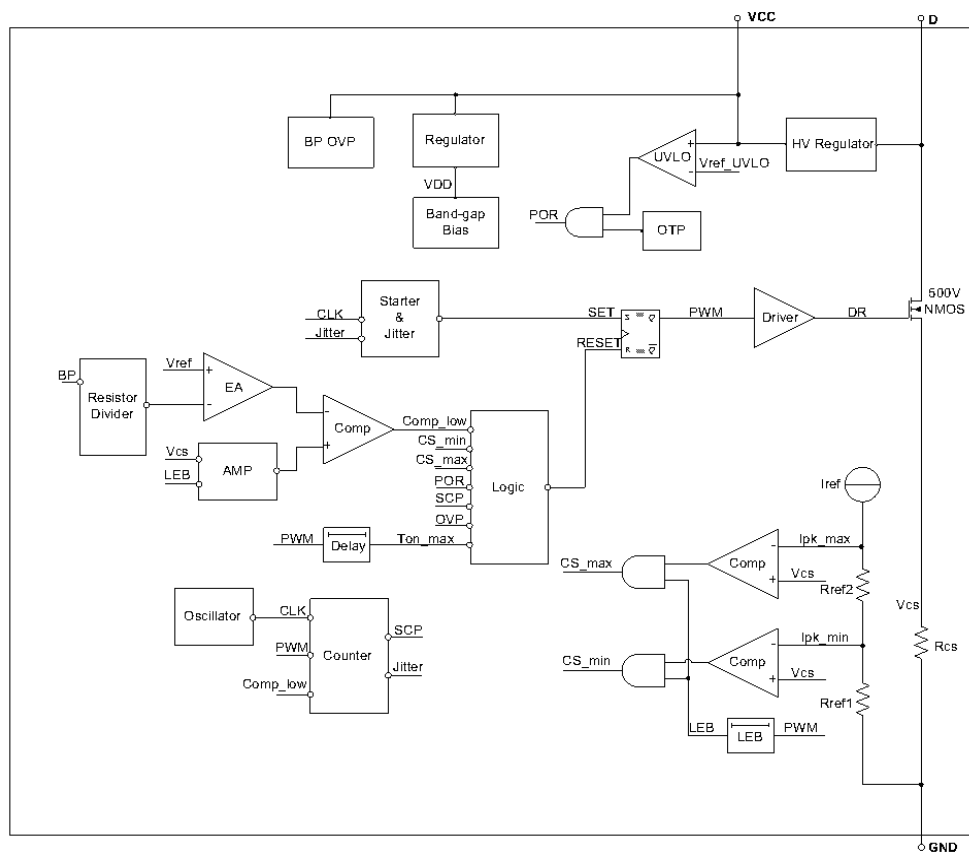


Figure3: HM2710B Block Diagram

ELECTRICAL CHARACTERISTICS

(VCC= 5V, T_A = 25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Operating Current	Is1	Non-Switching		610		uA
	Is2	Switching		670		uA
VCC Charge Current	ICH1	VCC=0V		1.57		mA
	ICH2	VCC=4V		1.33		mA
VCC UVLO	UVLO_H	VCC rising		4.7		V
	UVLO_L	VCC falling		4.2		V
VCC OVP	OVP_H	VCC rising		8.6		V
Maximum On Time	Ton_max			6		uS
Leading Edge Blanking Time	LEB			300		nS
Operating Frequency	F_OP			47		KHz
Minimum Peak Current	Min.Ipeak			150		mA
Maximum Peak Current	Max.Ipeak			300		mA
Over-Temperature Protection	OTP_H	Temperature-rising		150		°C
	OTP_L	Temperature-falling		75		°C
On Resistance	RDSON	ID=50mA		26		Ω
Drain-Source Leakage Current	ILeakage	VD=450V			15	uA
Drain-Source breakdown voltage	BVDSS		500			V
Driving rising time	Tr			80		nS
Driving falling time	Tf			40		nS
Maximum Output current @Vout=5V	Iout_max	220Vac	120			mA
		110Vac	110			mA
Startup time	Tstart				50	mS
Maximum loading Current @Startup	Iload_st		110			mA

Table 2

APPLICATION INFORMANCE

Power Supply and Standby Power

HM2710B integrates a 500V startup circuit, which can charge the VCC to 5V directly from Drain pin, so as to reduce traditional startup resistor. Once the output voltage is above 5V, the 500V startup circuit will shutdown to reduce standby power. HM2710B standby power is typically lower than 50mW.

VCC UVLO

A UVLO comparator with built-in hysteresis is implemented in PT Ģ FĖÓ, with turn-on and turn-off threshold set at 4.7V and 4.2V respectively.

Over Voltage Protection

When VCC voltage is higher than the OVP threshold voltage 8.5V, PT Ģ FĖÓ will shutdown the Power MOS immediately, meanwhile a 1mA current will through from VCC to GND.

High Accuracy Control

HM2710B implements high performance error amplifier and accurate reference, to ensure the output accuracy and line/load regulation.

Frequency Jittering

HM2710B is a WM switcher, with a fixed frequency 47KHz. PT Ģ FĖÓ implements a $\pm 5\%$ frequency jittering, which can effectively improving EMI performance

Leading Edge Blanking

Each time the power MOSFET is switched on, a turn-on spike will inevitably occur across the internal sense resistor. To avoid false trigger, a 300ns leading-edge blanking time is built in. During this blanking period, the current-limit comparator is disabled and can not switch off the gate driver.

Over Current Protection

The HM2710B has the over current protection function built in. An internal circuit detects the power MOS current level, when the current is larger than a threshold level, the gate output will switch off immediately until next cycle.

Over Temperature Protection

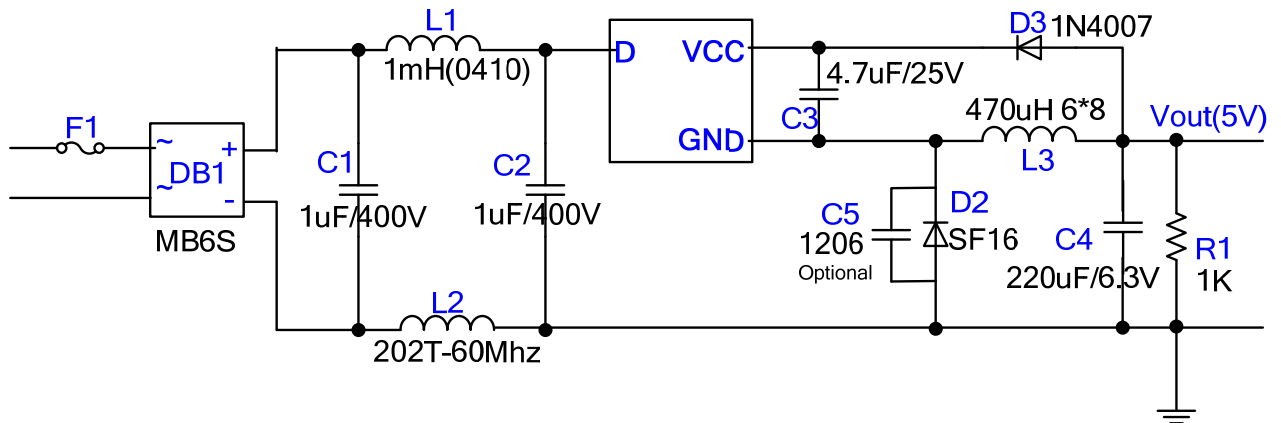
When temperature is higher than OTP threshold 150°C, PT Ģ FĖÓ will shutdown the power MOS. Until temperature is lower than 75°C, the power MOS will work normally.

Short Circuit Protection

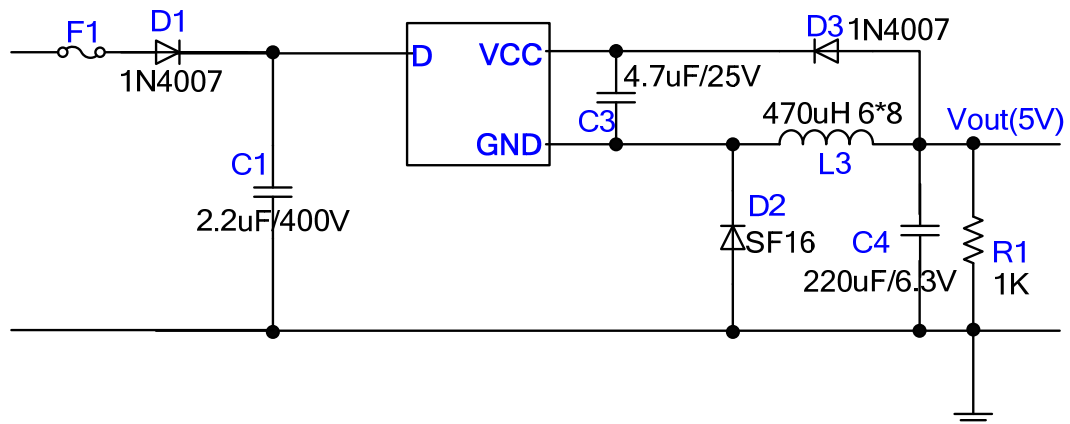
When short circuit happens, HM2710B will enter “auto-restart” mode. If the output feedback voltage is larger than internal setting reference for over 3072 cycles, than the power MOS will shutdown for 500mS.

Typical Application Project

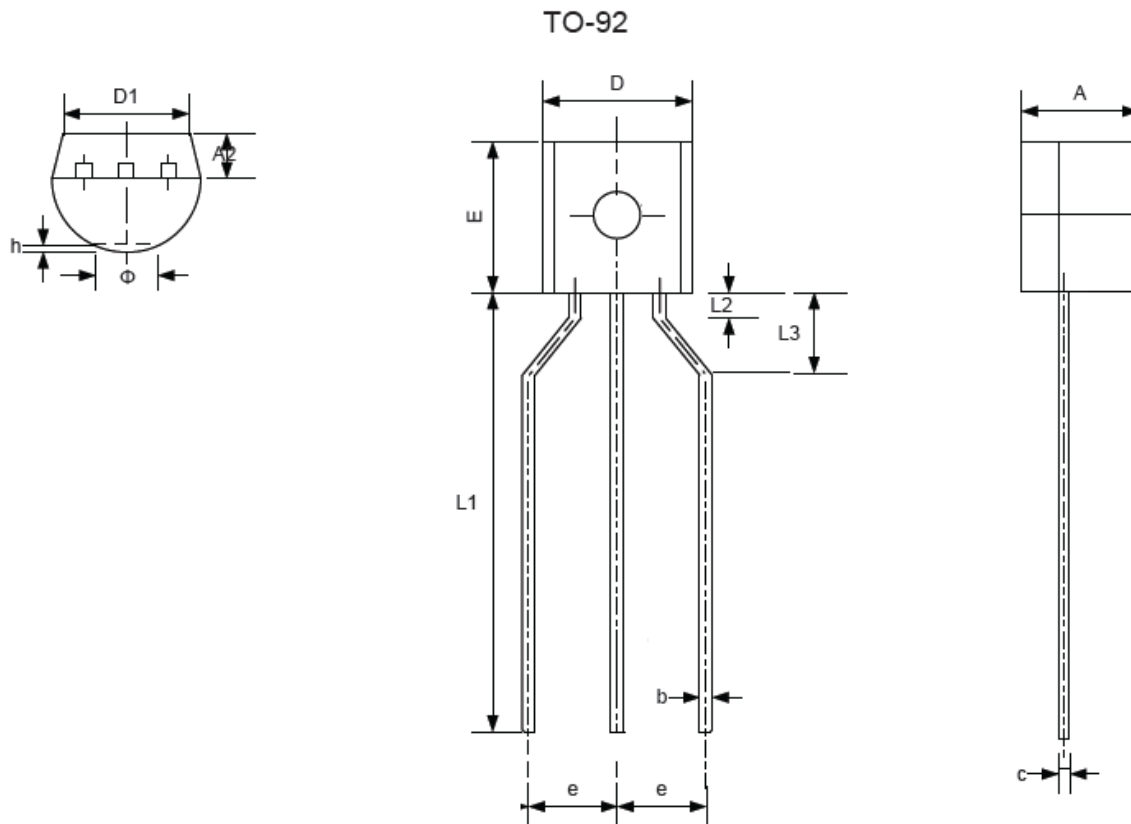
Project1: EMC-Requirement (5V0.12A)



Project2: None EMC-Requirement (5V0.12A)

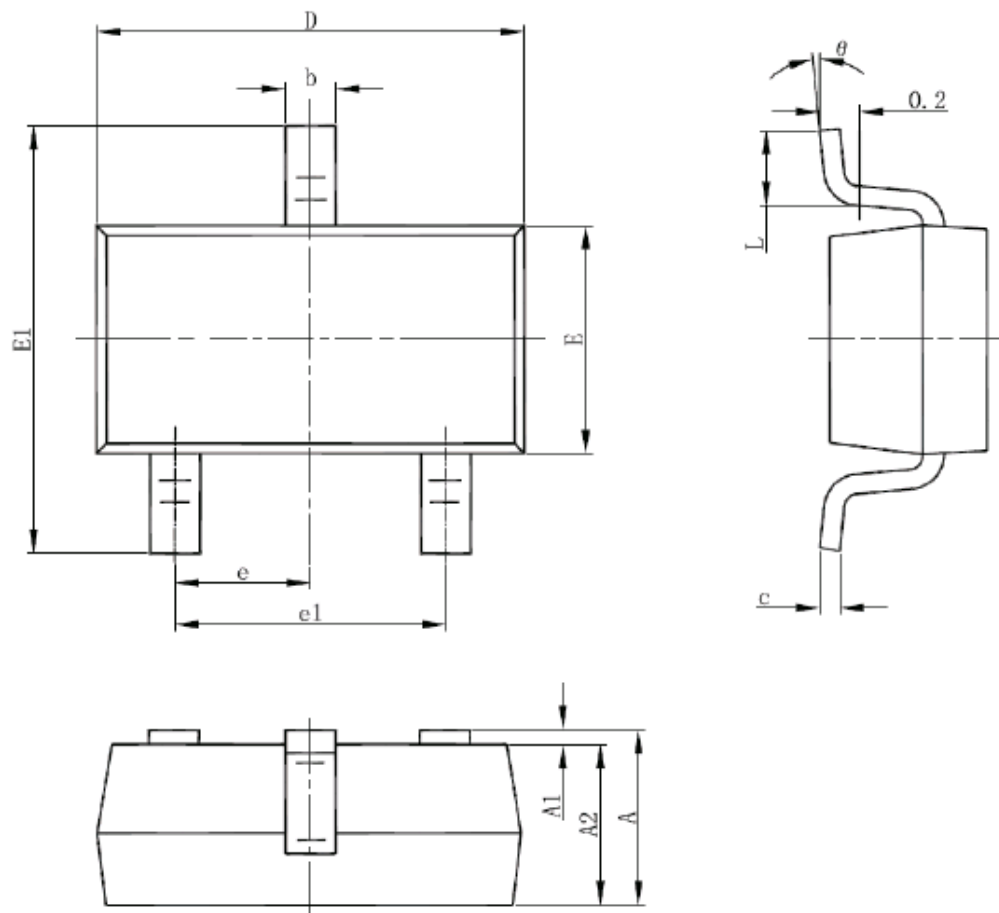


Package Figure (TO-92)



Symbol	Size (mm)		Size (inch)	
	min	max	min	max
A	3.300	3.700	0.130	0.146
A2	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.400	4.700	0.173	0.185
D1	3.430	-	0.135	-
E	4.300	4.700	0.169	0.185
e	2.440	2.640	0.096	0.104
h	0.000	0.380	0.000	0.015
L1	12.50	14.500	0.492	0.571
L3	2.500	3.500	0.098	0.138
θ	-	1.600	-	0.063

Package Figure (SOT23-3)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°